SLLS857-AUGUST 2007

FEATURES

- Operates With 3-V to 5.5-V V_{CC} Supply
- · Operates up to 1 Mbit/s
- Low Standby Current . . . 1 μA Typ
- External Capacitors . . . $4 \times 0.1 \mu F$
- Accepts 5-V Logic Input With 3.3-V Supply
- RS-232 Bus-Pin ESD Protection Exceeds ±15 kV Using Human-Body Model (HBM)
- Auto-Powerdown Feature Automatically Disables Drivers for Power Savings

APPLICATIONS

- Battery-Powered, Hand-Held, and Portable Equipment
- PDAs and Palmtop PCs
- Notebooks, Sub-Notebooks, and Laptops
- Digital Cameras
- Mobile Phones and Wireless Devices

16 FORCEOFF EN [$C1 + \Pi_2$ 15 V_{CC} V+ **[**]3 14 GND C1- Π_4 13 DOUT 12 FORCEON C2+ []5 C2- П6 11 ∏ DIN V− **[**]7 10 INVALID RIN []8 9 ROUT

DB OR PW PACKAGE

(TOP VIEW)

DESCRIPTION/ORDERING INFORMATION

The TRSF3221 consists of one line driver, one line receiver, and a dual charge-pump circuit with ±15-kV IEC ESD protection pin-to-pin (serial-port connection pins, including GND). The TRSF3221 provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The TRSF3221 operates at data signaling rates up to 1 Mbit/s and a driver output slew rate of 24 V/µs to 150 V/µs.

Flexible control options for power management are available when the serial port is inactive. The auto-powerdown feature functions when FORCEON is low and $\overline{FORCEOFF}$ is high. During this mode of operation, if the TRSF3221 does not sense a valid RS-232 signal on the receiver input, the driver output is disabled. If $\overline{FORCEOFF}$ is set low and the enable (\overline{EN}) input is high, both the driver and receiver are shut off, and the supply current is reduced to 1 μA . Disconnecting the serial port or turning off the peripheral drivers causes the auto-powerdown condition to occur. Auto-powerdown can be disabled when FORCEON and $\overline{FORCEOFF}$ are high. With auto-powerdown enabled, the device is activated automatically when a valid signal is applied to the receiver input. The $\overline{INVALID}$ output notifies the user if an RS-232 signal is present at the receiver input. $\overline{INVALID}$ is high (valid data) if the receiver input voltage is greater than 2.7 V or less than -2.7 V, or has been between -0.3 V and 0.3 V for less than 30 μs . $\overline{INVALID}$ is low (invalid data) if the receiver input voltage is between -0.3 V and 0.3 V for more than 30 μs . See Figure 5 for receiver input levels.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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ORDERING INFORMATION

T _A	PACKAG	6E ⁽¹⁾⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SSOP - DB	Reel of 2000	TRSF3221CDBR	RT21C
0°C to 70°C	TSSOP – PW	Tube of 90	TRSF3221CPW	RT21C
	1330F - FW	Reel of 2000	TRSF3221CPWR	KIZIC
	SSOP – DB	Reel of 2000	TRSF3221IDBR	RT21I
-40°C to 85°C	TSSOP – PW	Tube of 90	TRSF3221IPW	RT21I
	1330P - PW	Reel of 2000	TRSF3221IPWR	RIZII

- (1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

FUNCTION TABLES

Each Driver(1)

	I	NPUTS		ОИТРИТ	
DIN	FORCEON	FORCEOFF	VALID RIN RS-232 LEVEL	DOUT	DRIVER STATUS
Х	X	L	X	Z	Powered off
L	Н	Н	X	Н	Normal operation with
Н	Н	Н	X	L	auto-powerdown disabled
L	L	Н	Yes	Н	Normal operation with
Н	L	Н	Yes	L	auto-powerdown enabled
L	L	Н	No	Z	Powered off by
Н	L	Н	No	Z	auto-powerdown feature

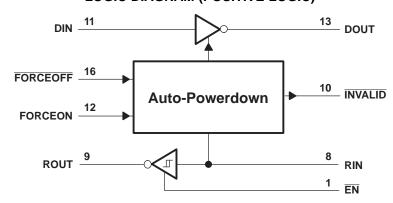
(1) H = high level, L = low level, X = irrelevant, Z = high impedance

Each Receiver(1)

	INPUTS		
RIN	EN	VALID RIN RS-232 LEVEL	OUTPUT ROUT
L	L	X	Н
Н	L	X	L
X	Н	X	Z
Open	L	No	Н

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = disconnected input or connected driver off

LOGIC DIAGRAM (POSITIVE LOGIC)



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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range ⁽²⁾		-0.3	6	V
V+	Positive-output supply voltage range (2)		-0.3	7	V
V-	Negative-output supply voltage range (2)		0.3	-7	V
V+ - V-	Supply voltage difference ⁽²⁾			13	V
V	Input voltage range	Driver (FORCEOFF, FORCEON, EN)	-0.3	6	V
V _I	Receiver	-25	25	V	
\/	Outrot valtage respect	Driver	-13.2	13.2	V
Vo	Output voltage range	Receiver (INVALID)	-0.3	V _{CC} + 0.3	V
0	Package thermal impedance (3)(4)	DB package		82	°C/W
θ_{JA}	Package thermal impedance (57.7)	PW package		108	-C/VV
TJ	Operating virtual junction temperature			150	°C
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltages are with respect to network GND.

Recommended Operating Conditions⁽¹⁾

See Figure 6

				MIN	NOM	MAX	UNIT
	Supply voltage		V _{CC} = 3.3 V	3	3.3	3.6	V
	Supply voltage	$V_{CC} = 5 V$	4.5	5	5.5	V	
\/	Driver and control	DIN, FORCEOFF, FORCEON, EN	$V_{CC} = 3.3 \text{ V}$	2			V
V _{IH}	high-level input voltage	DIN, FORCEOFF, FORCEON, EN	$V_{CC} = 5 V$	2.4			V
V _{IL}	Driver and control low-level input voltage	DIN, FORCEOFF, FORCEON, EN				0.8	V
VI	Driver and control input voltage	DIN, FORCEOFF, FORCEON		0		5.5	V
VI	Receiver input voltage			-25		25	V
т	Operating free air temperature		TRSF3221I	-40		85	°C
T _A	Operating free-air temperature		TRSF3221C	0		70	C

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARA	METER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
I	Input leakage current	FORCEOFF, FORCEON, EN			±0.01	±1	μA
		Auto-powerdown disabled	No load, FORCEOFF and FORCEON at V _{CC}		0.3	1	mA
Icc	Supply current	Powered off	No load, FORCEOFF at GND		1	10	
·cc	(T _A = 25°C)	Auto-powerdown enabled	No load, FORCEOFF at V _{CC} , FORCEON at GND, All RIN are open or grounded		1	10	μΑ

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

The package thermal impedance is calculated in accordance with JESD 51-7.





DRIVER SECTION

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST	CONDITIONS		MIN	TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	DIN = GND		5	5.4		V
V_{OL}	Low-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	$DIN = V_{CC}$		-5	-5.4		V
I _{IH}	High-level input current	$V_I = V_{CC}$				±0.01	±1	μA
I _{IL}	Low-level input current	V _I at GND				±0.01	±1	μA
	Short-circuit	V _O = 0 V	V _{CC} = 3.6 V			±35	±60	mA
los	output current ⁽³⁾	v _O = 0 v	$V_{CC} = 5.5 \text{ V}$			±35	±90	ША
ro	Output resistance	V_{CC} , V+, and V- = 0 V,	$V_O = \pm 2 V$		300	10M		Ω
	Output lookage ourrent	FORCEOFF = GND	$V_0 = \pm 12 V$,	V _{CC} = 3 V to 3.6 V			±25	
I _{off}	Output leakage current	FURGEOFF = GND	$V_{O} = \pm 10 \text{ V},$	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$			±25	μA

Switching Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

F	PARAMETER		TEST CONDITIONS		MIN	TYP ⁽²⁾	MAX	UNIT
Maximum data rate (see Figure 1)			C _L = 1000 pF		250			
		$R_L = 3 k\Omega$	$C_L = 250 \text{ pF},$	V_{CC} = 3 V to 4.5 V	1000			kbit/s
(00011	iguio 1)		C _L = 1000 pF,	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	1000			
t _{sk(p)}	Pulse skew ⁽³⁾	$C_L = 150 \text{ pF to } 2500 \text{ pF},$	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	See Figure 2		100		ns
SR(tr)	Slew rate, transition region (see Figure 1)	V _{CC} = 3.3 V,	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	C _L = 150 pF to 1000 pF	18		150	V/µs

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.

ESD Protection

TERMI	NAL	TEST CONDITIONS	TVD	UNIT
NAME	NO.	TEST COMPITIONS		UNIT
DOUT	13	HBM	±15	kV

Product Folder Link(s): TRSF3221

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 ⁽¹⁾ Test conditions are C1–C4 = 0.1 μF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2–C4 = 0.33 μF at V_{CC} = 5 V ± 0.5 V.
(2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.
(3) Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.



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RECEIVER SECTION

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	$I_{OH} = -1 \text{ mA}$	V _{CC} - 0.6	$V_{CC} - 0.1$		V
V_{OL}	Low-level output voltage	I _{OL} = 1.6 mA			0.4	V
V	Desitive going input threshold voltage	V _{CC} = 3.3 V		1.6	2.4	V
V _{IT+}	Positive-going input threshold voltage	V _{CC} = 5 V		1.9	2.4	V
V	Negative-going input threshold voltage	V _{CC} = 3.3 V	0.6	1.1		V
V _{IT}	Negative-going input tilleshold voltage	V _{CC} = 5 V	0.8	1.4		V
V _{hys}	Input hysteresis (V _{IT+} - V _{IT-})			0.5		V
I _{off}	Output leakage current	FORCEOFF = 0 V		±0.05	±10	μΑ
r _i	Input resistance	V _I = ±3 V to ±25 V	3	5	7	kΩ

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V. (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

Switching Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST CONDITIONS	TYP ⁽²⁾	UNIT
t _{PLH}	Propagation delay time, low- to high-level output	C _L = 150 pF, See Figure 3	150	ns
t _{PHL}	Propagation delay time, high- to low-level output	C _L = 150 pF, See Figure 3	150	ns
t _{en}	Output enable time	$C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega, \text{ See Figure 4}$	200	ns
t _{dis}	Output disable time	$C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega, \text{ See Figure 4}$	200	ns
t _{sk(p)}	Pulse skew ⁽³⁾	See Figure 3	50	ns

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.

ESD Protection

TERMI	NAL	TEST CONDITIONS	TVD	UNIT
NAME	NO.	TEST CONDITIONS	ITP	UNII
RIN	8	НВМ	±15	kV

Product Folder Link(s): TRSF3221

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AUTO-POWERDOWN SECTION

Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST COI	MIN	MAX	UNIT	
V _{T+(valid)}	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND,	FORCEOFF = V _{CC}		2.7	V
V _{T-(valid)}	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND,	FORCEOFF = V _{CC}	-2.7		٧
V _{T(invalid)}	Receiver input threshold for INVALID low-level output voltage	FORCEON = GND,	FORCEOFF = V _{CC}	-0.3	0.3	٧
V _{OH}	INVALID high-level output voltage	I _{OH} = -1 mA, FORCEON FORCEOFF = V _{CC}	I = GND,	V _{CC} - 0.6		V
V _{OL}	INVALID low-level output voltage	I _{OL} = 1.6 mA, FORCEON FORCEOFF = V _{CC}	N = GND,		0.4	V

Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TYP ⁽¹⁾	UNIT
t _{valid}	Propagation delay time, low- to high-level output	1	μs
t _{invalid}	Propagation delay time, high- to low-level output	30	μs
t _{en}	Supply enable time	100	μs

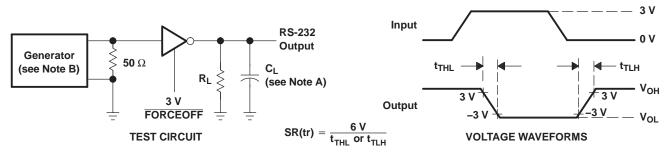
⁽¹⁾ All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

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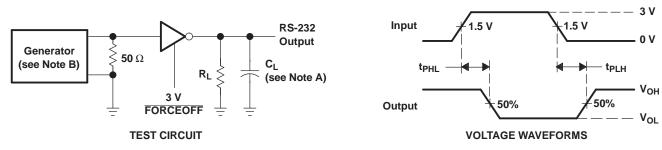
PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, Z_0 = 50 Ω , 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.

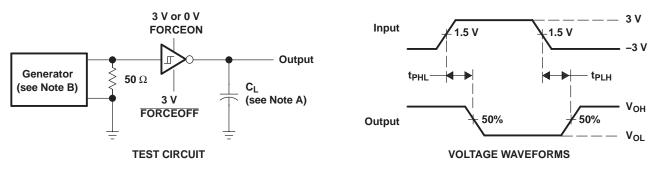
Figure 1. Driver Slew Rate



NOTES: A. C₁ includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.

Figure 2. Driver Pulse Skew



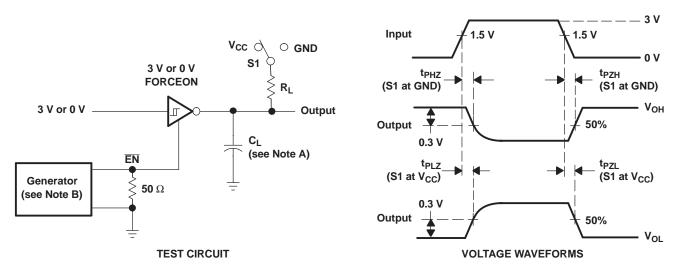
NOTES: A. C₁ includes probe and jig capacitance.

B. The pulse generator has the following characteristics: Z_O = 50 Ω , 50% duty cycle, $t_r \le$ 10 ns, $t_f \le$ 10 ns.

Figure 3. Receiver Propagation Delay Times



PARAMETER MEASUREMENT INFORMATION (continued)



NOTES: A. C_L includes probe and jig capacitance.

- B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.
- C. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- D. t_{PZL} and t_{PZH} are the same as t_{en}.

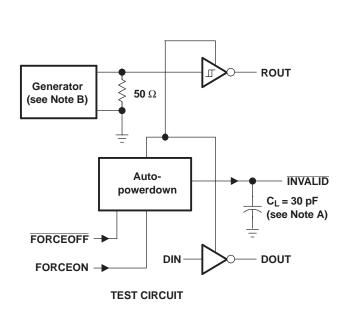
Figure 4. Receiver Enable and Disable Times

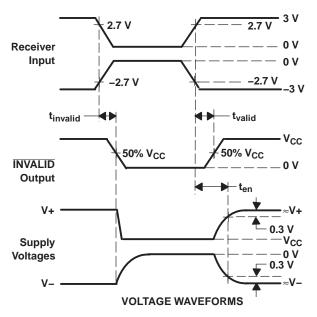
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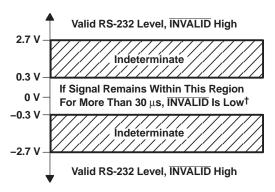
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PARAMETER MEASUREMENT INFORMATION (continued)







 $^{^{\}dagger}$ Auto-powerdown disables drivers and reduces supply current to 1 $\mu A.$

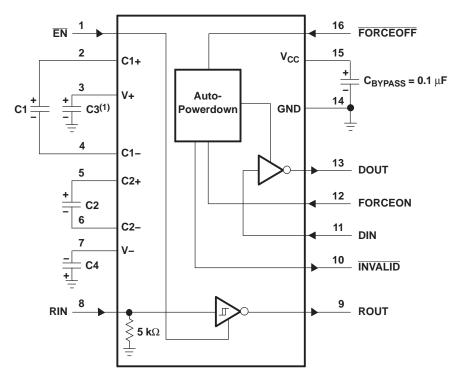
NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 5 kbit/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.

Figure 5. INVALID Propagation Delay Times and Driver Enabling Time



APPLICATION INFORMATION



(1) C3 can be connected to V_{CC} or GND. NOTES: A. Resistor values shown are nominal.

V_{CC} vs CAPACITOR VALUES

V _{CC}	C1	C2, C3, and C4
$\begin{array}{c} \textbf{3.3 V} \pm \textbf{0.3 V} \\ \textbf{5 V} \pm \textbf{0.5 V} \\ \textbf{3 V to 5.5 V} \end{array}$	0.1 μF 0.047 μF 0.1 μF	0.1 μF 0.33 μF 0.47 μF

Figure 6. Typical Operating Circuit and Capacitor Values

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24-Jul-2010

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
TRSF3221CDB	ACTIVE	SSOP	DB	16		TBD	Call TI	Call TI	Purchase Samples
TRSF3221CDBG4	ACTIVE	SSOP	DB	16		TBD	Call TI	Call TI	Purchase Samples
TRSF3221CDBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
TRSF3221CDBRG4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
TRSF3221CPW	ACTIVE	TSSOP	PW	16		TBD	Call TI	Call TI	Purchase Samples
TRSF3221CPWG4	ACTIVE	TSSOP	PW	16		TBD	Call TI	Call TI	Purchase Samples
TRSF3221CPWR	ACTIVE	TSSOP	PW	16		TBD	Call TI	Call TI	Purchase Samples
TRSF3221CPWRG4	ACTIVE	TSSOP	PW	16		TBD	Call TI	Call TI	Purchase Samples
TRSF3221IDB	ACTIVE	SSOP	DB	16		TBD	Call TI	Call TI	Purchase Samples
TRSF3221IDBG4	ACTIVE	SSOP	DB	16		TBD	Call TI	Call TI	Purchase Samples
TRSF3221IDBR	ACTIVE	SSOP	DB	16		TBD	Call TI	Call TI	Purchase Samples
TRSF3221IDBRG4	ACTIVE	SSOP	DB	16		TBD	Call TI	Call TI	Purchase Samples
TRSF3221IPW	ACTIVE	TSSOP	PW	16		TBD	Call TI	Call TI	Purchase Samples
TRSF3221IPWG4	ACTIVE	TSSOP	PW	16		TBD	Call TI	Call TI	Purchase Samples
TRSF3221IPWR	ACTIVE	TSSOP	PW	16		TBD	Call TI	Call TI	Purchase Samples
TRSF3221IPWRG4	ACTIVE	TSSOP	PW	16		TBD	Call TI	Call TI	Purchase Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

24-Jul-2010

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

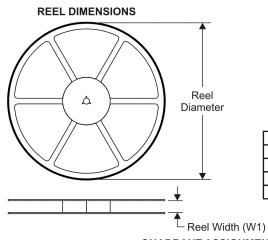
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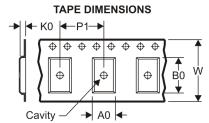
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 23-Jul-2010

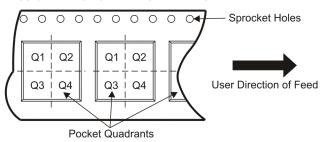
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
	Overall width of the carrier tape
P1	Pitch between successive cavity centers

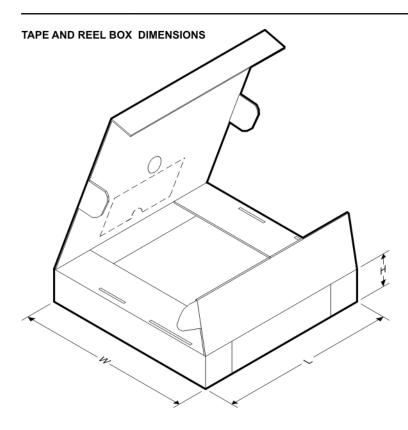
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRSF3221CDBR	SSOP	DB	16	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1

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*All dimensions are nominal

I	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
I	TRSF3221CDBR	SSOP	DB	16	2000	346.0	346.0	33.0

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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